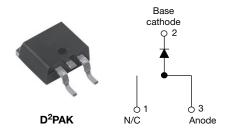


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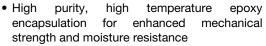
Schottky Rectifier, 16 A



PRODUCT SUMMARY							
I _{F(AV)}	16 A						
V _R	35 V/45 V						
I _{RM}	40 mA at 125 °C						

FEATURES

- 150 °C T_J operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

This VS-MBRB16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	16	А						
V _{RRM}		35/45	V						
I _{FSM}	t _p = 5 μs sine	1800	A						
V _F	16 Apk, T _J = 125 °C	0.57	V						
T _J		- 65 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB1635PbF	VS-MBRB1645PbF	UNITS					
Maximum DC reverse voltage	V_{R}	35	45	V					
Maximum working peak reverse voltage	V_{RWM}	33	45	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONI	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T _C = 134 °C, rated V _R	16						
Non-repetitive peak surge current	I _{FSM}	Following any rated 5 μs sine or 3 μs rect. pulse load condition and with rated V _{RRM} applied		1800	A				
		Surge applied at rated load single phase 60 Hz	150						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.6 \text{A}, L = 3.6 \text{A}$	24	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to Frequency limited by T _J max	3.6	А					

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VS-MBRB1635PbF, VS-MBRB1645PbF

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop	V (1)	16 A	T _J = 25 °C	0.63	V			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _J = 125 °C	0.57				
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA			
reverse current		T _J = 125 °C	hated DC voltage	40				
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	1400	pF				
Typical series inductance	L _S	Measured lead from top of	8.0	nΗ				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature	range	T_J		- 65 to 150	°C			
Maximum storage temperature	range	T_{Stg}		- 65 to 175	C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.50	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV			
Approximate weight				2	g			
				0.07	OZ.			
Mounting torque minimum				6 (5)	kgf · cm			
- Woulding torque	maximum			12 (10)	(lbf \cdot in)			
Marking device			Case style D ² PAK	MBRE	31645			



Schottky Rectifier, 16 A

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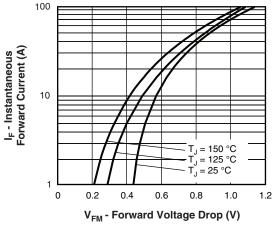


Fig. 1 - Maximum Forward Voltage Drop Characteristics

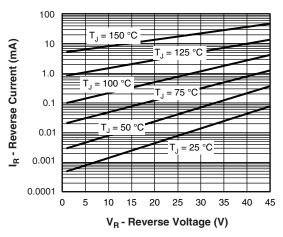


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

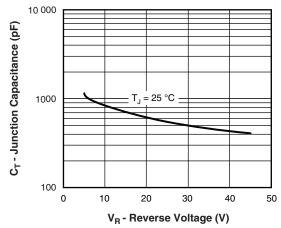


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

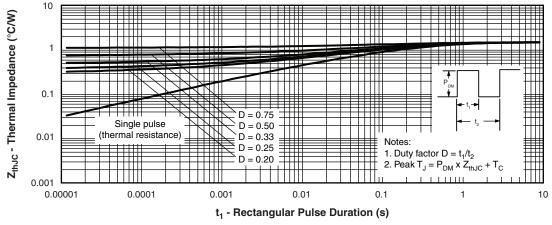


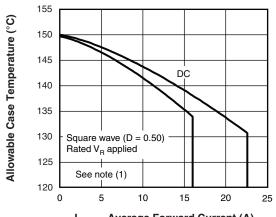
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

VS-MBRB1635PbF, VS-MBRB1645PbF

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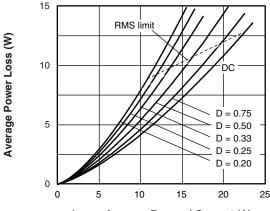
Schottky Rectifier, 16 A





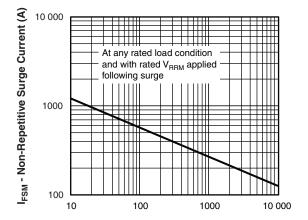
I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current



I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

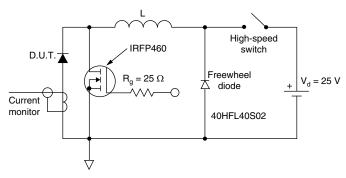


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \text{ applied} \\ \end{array}$



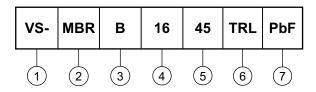
VS-MBRB1635PbF, VS-MBRB1645PbF

Schottky Rectifier, 16 A

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ORDERING INFORMATION TABLE

Device code



1 - HPP product suffix

2 - Essential part number

B = Surface mount

Current rating (16 = 16 A)

5 - Voltage code = V_{RRM} 35 = 35 V 45 = 45 V

6 - • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

7 - PbF = Lead (Pb)-free

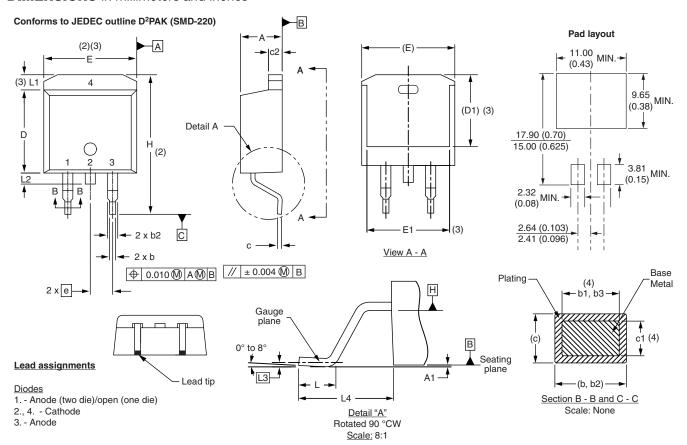
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95407					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	HES NOTES		SYMBOL	MILLIM	ETERS	INC	HES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB

NOTES

3

2, 3

3

3



Legal Disclaimer Notice

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